

1N4933-1N4937

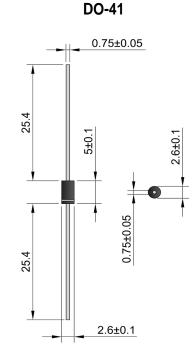
1.0A FAST RECOVERY DIODE

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: DO-41, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.35 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Lead Free: For RoHS / Lead Free Version



Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	1N4933	1N4934	1N4935	1N4936	1N4937	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	V
Average Rectified Output Current (Note 1) $@T_A = 75^{\circ}C$	lo	1.0					А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	IFSM	30					A
Forward Voltage $@I_F = 1.0A$	Vfm	1.2					V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	Iгм	5.0 100					μA
Reverse Recovery Time (Note 2)	t _{rr}	200					nS
Typical Junction Capacitance (Note 3)	CJ	12					pF
Typical Thermal Resistance Junction to Ambient (Note 1) Typical Thermal Resistance Junction to Lead (Note 1)	R JA R JL	55 25					°C/W
Operating Temperature Range	TJ	-65 to +125					°C
Storage Temperature Range	Тѕтс	-65 to +150					°C

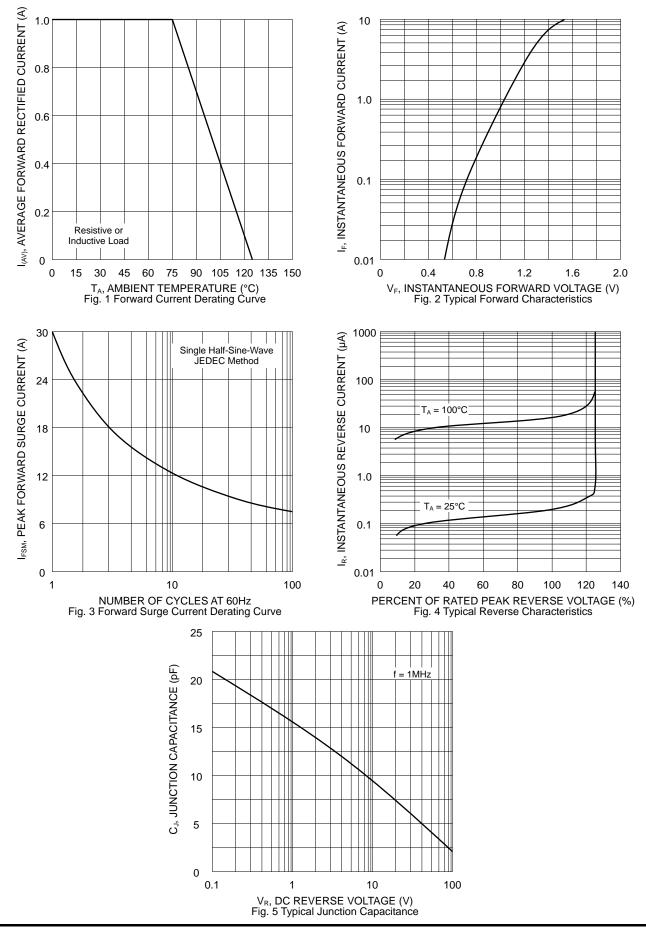
Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

2. Measured with $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$.

3. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.

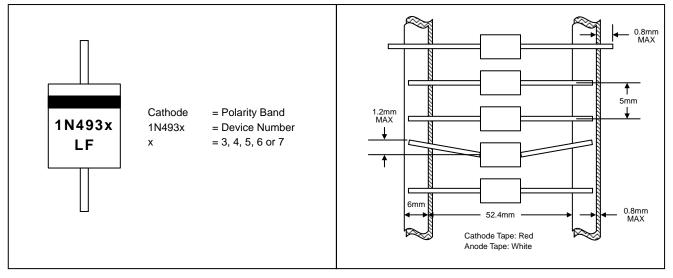


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MARKING INFORMATION



TAPING SPECIFICATIONS

PACKAGING INFORMATION

